

**Vishay Semiconductors** 

### **Silicon NPN Phototransistor**



### DESCRIPTION

VEMT2500X01 series are silicon NPN epitaxial planar phototransistors in a miniature dome lens, clear epoxy package for surface mounting. The device is sensitive to visible and near infrared radiation.

#### FEATURES

- Package type: surface mount
- Package form: GW, RGW
- Dimensions (L x W x H in mm): 2.3 x 2.3 x 2.8
- AEC-Q101 qualified
- High radiant sensitivity
- Suitable for visible and near infrared radiation
- Fast response times
- Angle of half sensitivity:  $\phi = \pm 15^{\circ}$
- Package matched with IR emitter series VSMB2000X01
- Floor life: 4 weeks, MSL 2a, acc. J-STD-020
- Lead (Pb)-free reflow soldering
- Compliant to RoHS Directive 2002/95/EC and in accordance to WEEE 2002/96/EC
- Halogen-free according to IEC 61249-2-21 definition

#### **APPLICATIONS**

- Detector in automotive applications
- Photo interrupters
- Miniature switches
- Counters
- Encoders
- Position sensors

| PRODUCT SUMMARY |                      |         |                       |
|-----------------|----------------------|---------|-----------------------|
| COMPONENT       | I <sub>ca</sub> (mA) | φ (deg) | λ <sub>0.1</sub> (nm) |
| VEMT2500X01     | 6                    | ± 15    | 470 to 1090           |
| VEMT2520X01     | 6                    | ± 15    | 470 to 1090           |

Note

· Test condition see table "Basic Characteristics"

| ORDERING INFORMATION |                              |                              |                  |  |
|----------------------|------------------------------|------------------------------|------------------|--|
| ORDERING CODE        | ING CODE PACKAGING REMARKS P |                              | PACKAGE FORM     |  |
| VEMT2500X01          | Tape and reel                | MOQ: 6000 pcs, 6000 pcs/reel | Reverse gullwing |  |
| VEMT2520X01          | Tape and reel                | MOQ: 6000 pcs, 6000 pcs/reel | Gullwing         |  |

Note

• MOQ: minimum order quantity

| <b>ABSOLUTE MAXIMUM RATINGS</b> (T <sub>amb</sub> = 25 °C, unless otherwise specified) |                              |                  |               |      |  |
|--|------------------------------|------------------|---------------|------|--|
| PARAMETER  | TEST CONDITION               | SYMBOL           | VALUE         | UNIT |  |
| Collector emitter voltage  |                              | V <sub>CEO</sub> | 20            | V    |  |
| Emitter collector voltage  |                              | V <sub>ECO</sub> | 7             | V    |  |
| Collector current  |                              | Ι <sub>C</sub>   | 50            | mA   |  |
| Power power dissipation  | $T_{amb} \le 75 \ ^{\circ}C$ | P <sub>V</sub>   | 100           | mW   |  |
| Junction temperature   |                              | Tj               | 100           | °C   |  |
| Operating temperature range  |                              | T <sub>amb</sub> | - 40 to + 100 | °C   |  |



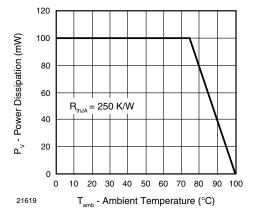


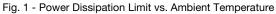
Vishay Semiconductors

Silicon NPN Phototransistor



| ABSOLUTE MAXIMUM RATINGS (T <sub>amb</sub> = 25 °C, unless otherwise specified) |                            |                   |               |      |  |
|---|----------------------------|-------------------|---------------|------|--|
| PARAMETER   | TEST CONDITION             | SYMBOL VAL        |               | UNIT |  |
| Storage temperature range   |                            | T <sub>stg</sub>  | - 40 to + 100 | °C   |  |
| Soldering temperature   | Acc. reflow profile fig. 8 | T <sub>sd</sub>   | 260           | °C   |  |
| Thermal resistance junction/ambient   | Acc. J-STD-051             | R <sub>thJA</sub> | 250           | K/W  |  |



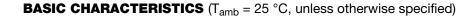


| <b>BASIC CHARACTERISTICS</b> (T <sub>amb</sub> = 25 °C, unless otherwise specified) |  |                    |      |             |      |      |
|---|--|--------------------|------|-------------|------|------|
| PARAMETER   | TEST CONDITION   | SYMBOL             | MIN. | TYP.        | MAX. | UNIT |
| Collector emitter breakdown voltage   | I <sub>C</sub> = 0.1 mA  | V <sub>CEO</sub>   | 20   |             |      | V    |
| Collector dark current  | $V_{CE} = 5 V, E = 0$  | I <sub>CEO</sub>   |      | 1           | 100  | nA   |
| Collector emitter capacitance   | $V_{CE} = 0 V, f = 1 MHz, E = 0$   | C <sub>CEO</sub>   |      | 25          |      | pF   |
| Collector light current   | $\begin{array}{l} E_{e} = 1 \ mW/cm^2,  \lambda = 950 \ nm, \\ V_{CE} = 5 \ V \end{array}$ | I <sub>CA</sub>    | 3    | 6           | 9    | mA   |
| Angle of half sensitivity   |  | φ                  |      | ± 15        |      | deg  |
| Wavelength of peak sensitivity  |  | λp                 |      | 850         |      | nm   |
| Range of spectral bandwidth   |  | λ <sub>0.1</sub>   |      | 470 to 1090 |      | nm   |
| Collector emitter saturation voltage  | I <sub>C</sub> = 0.05 mA   | V <sub>CEsat</sub> |      |             | 0.4  | V    |
| Temperature coefficient of Ica  | $E_e = 1 \text{ mW/cm}^2, \lambda = 950 \text{ nm}, \\ V_{CE} = 5 \text{ V}$               | Tk <sub>ica</sub>  |      | 1.1         |      | %/K  |



### Silicon NPN Phototransistor

**Vishay Semiconductors** 



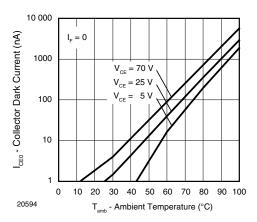


Fig. 2 - Collector Dark Current vs. Ambient Temperature

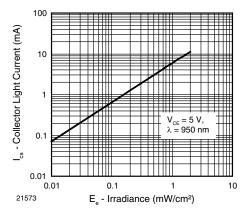


Fig. 3 - Collector Light Current vs. Irradiance

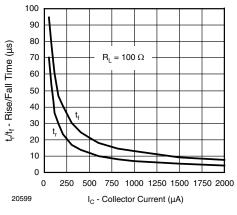


Fig. 4 - Rise/Fall Time vs. Collector Current

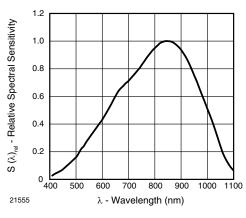


Fig. 5 - Relative Spectral Sensitivity vs. Wavelength

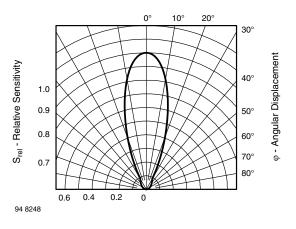


Fig. 6 - Relative Radiant Sensitivity vs. Angular Displacement

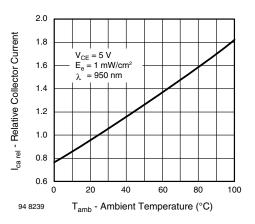


Fig. 7 - Relative Collector Current vs. Ambient Temperature

**Vishay Semiconductors** 

Silicon NPN Phototransistor



### **REFLOW SOLDER PROFILE**

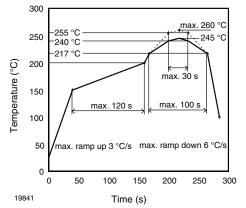
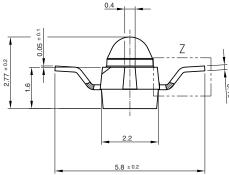
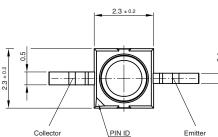
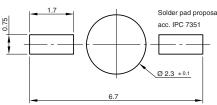


Fig. 8 - Lead (Pb)-free Reflow Solder Profile acc. J-STD-020

#### PACKAGE DIMENSIONS VEMT2500X01 in millimeters







Drawing-No.: 6.544-5391.01-4 Issue: 1; 26.09.08 21570



Devices are packed in moisture barrier bags (MBB) to prevent the products from moisture absorption during transportation and storage. Each bag contains a desiccant.

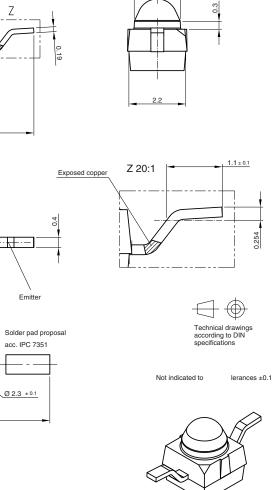
### **FLOOR LIFE**

Floor life (time between soldering and removing from MBB) must not exceed the time indicated on MBB label: Floor life: 4 weeks Conditions:  $T_{amb} < 30$  °C, RH < 60 % Moisture sensitivity level 2a, acc. to J-STD-020.

### DRYING

Ø 1.8 ± 0.1

In case of moisture absorption devices should be baked before soldering. Conditions see J-STD-020 or label. Devices taped on reel dry using recommended conditions 192 h at 40 °C (+ 5 °C), RH < 5 %.

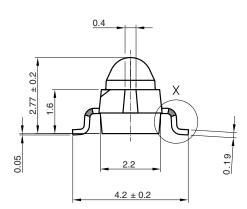


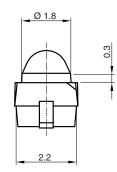


Silicon NPN Phototransistor

Vishay Semiconductors

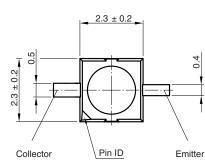
### PACKAGE DIMENSIONS VEMT2520X01 in millimeters

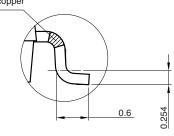




Exposed copper

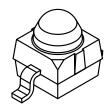
X 20:1

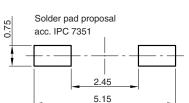






Not indicated tolerances ± 0.1





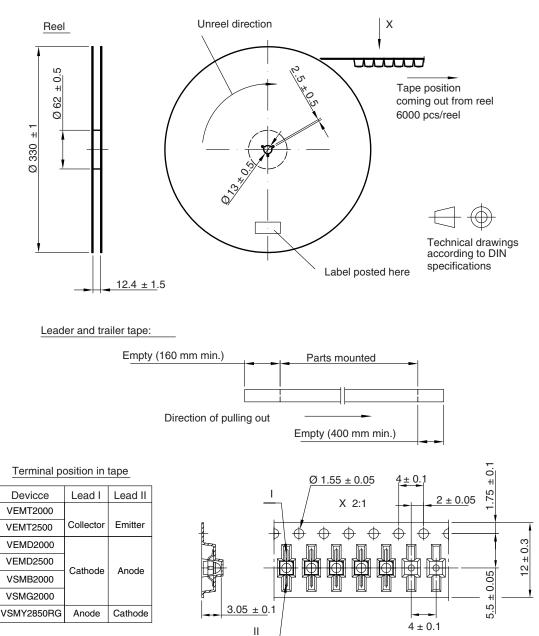
Drawing-No.: 6.544-5383.01-4 Issue: 4; 28.01.09 21569

**Vishay Semiconductors** 

Silicon NPN Phototransistor



### TAPE AND REEL DIMENSIONS VEMT2500X01 in millimeters



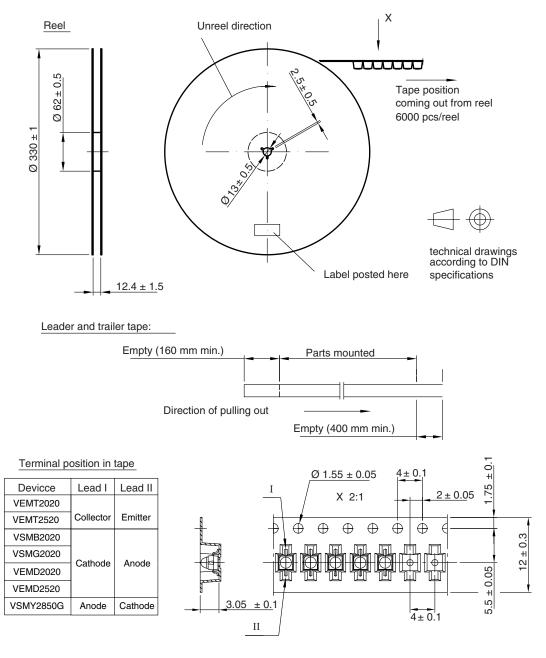
Drawing-No.: 9.800-5100.01-4 Issue: 2; 18.03.10 21572



Silicon NPN Phototransistor

**Vishay Semiconductors** 

### TAPE AND REEL DIMENSIONS VEMT2520X01 in millimeters



Drawing-No.: 9.800-5091.01-4 Issue: 3; 18.03.09 21571



Vishay

## Disclaimer

ALL PRODUCT, PRODUCT SPECIFICATIONS AND DATA ARE SUBJECT TO CHANGE WITHOUT NOTICE TO IMPROVE RELIABILITY, FUNCTION OR DESIGN OR OTHERWISE.

Vishay Intertechnology, Inc., its affiliates, agents, and employees, and all persons acting on its or their behalf (collectively, "Vishay"), disclaim any and all liability for any errors, inaccuracies or incompleteness contained in any datasheet or in any other disclosure relating to any product.

Vishay makes no warranty, representation or guarantee regarding the suitability of the products for any particular purpose or the continuing production of any product. To the maximum extent permitted by applicable law, Vishay disclaims (i) any and all liability arising out of the application or use of any product, (ii) any and all liability, including without limitation special, consequential or incidental damages, and (iii) any and all implied warranties, including warranties of fitness for particular purpose, non-infringement and merchantability.

Statements regarding the suitability of products for certain types of applications are based on Vishay's knowledge of typical requirements that are often placed on Vishay products in generic applications. Such statements are not binding statements about the suitability of products for a particular application. It is the customer's responsibility to validate that a particular product with the properties described in the product specification is suitable for use in a particular application. Parameters provided in datasheets and/or specifications may vary in different applications and performance may vary over time. All operating parameters, including typical parameters, must be validated for each customer application by the customer's technical experts. Product specifications do not expand or otherwise modify Vishay's terms and conditions of purchase, including but not limited to the warranty expressed therein.

Except as expressly indicated in writing, Vishay products are not designed for use in medical, life-saving, or life-sustaining applications or for any other application in which the failure of the Vishay product could result in personal injury or death. Customers using or selling Vishay products not expressly indicated for use in such applications do so at their own risk and agree to fully indemnify and hold Vishay and its distributors harmless from and against any and all claims, liabilities, expenses and damages arising or resulting in connection with such use or sale, including attorneys fees, even if such claim alleges that Vishay or its distributor was negligent regarding the design or manufacture of the part. Please contact authorized Vishay personnel to obtain written terms and conditions regarding products designed for such applications.

No license, express or implied, by estoppel or otherwise, to any intellectual property rights is granted by this document or by any conduct of Vishay. Product names and markings noted herein may be trademarks of their respective owners.